## SG -3032JC

# **Preliminary**

- Built-in crystal unit allows adjustment-free efficient operation.
- A general-purpose SMD
- Operating voltage 1.8 to3.6V

#### **■** Specifications

### 1. Absolute Max. Rating

Item	Symbol	Min.	Тур.	Max.	Unit	Remarks	
Power source voltage	Vdd	GND - 0.3		V <sub>DD</sub> + 0.3	V	V <sub>DD</sub> -GND	
Input voltage	Vin	GND - 0.3		V <sub>DD</sub> + 0.3	V	V <sub>DD</sub> -GND	
Storage temperature	Tstg	-55		+125	°C		
Operating Temperature	Topr	- 40		+85	ů		
Soldering condition	TsoL	Twice at under 260 °C within 10 sec. or under 230 °C within 3 min.					

#### 2. Characteristics

Item	Symbol	Min.	Тур.	Max.	Unit	Remarks
Output Frequency	fo		32.768		kHz	
Power source voltage	Vdd	1.8		3.6	V	
Frequency stability	∆f / fo	-20	5	30	ppm	+25°C,
						V <sub>DD</sub> =3.3V
Current consumption	IDD		3		μΑ	No load
						V <sub>DD</sub> =3.3V
Duty	tw/t	40	50	60	%	V <sub>DD</sub> /2 level
Output voltage	Voн			V <sub>DD</sub> -0.4	V	Iон= -0.5mA
	Vol	0.4			V	IoL= 0.5mA
Output rise time,	tr, tf			100	ns	20% to 80%
fall time						VDD
Oscillation start up time	tsta			3	S	
Aging	fa	- 5		5	ppm/Year	

#### **■** External dimensions

(Unit: mm) 10.5 max. No. Pin terminal <u>#</u>3 NC 1 2 **GND** SG3032 3 OUT 5.0 8123A 4 VDD #2 5.8 max. 0.2 0.51 5.08 (1.0) (1.0) 3.6